## 2SA1790J

## Silicon PNP epitaxial planar type

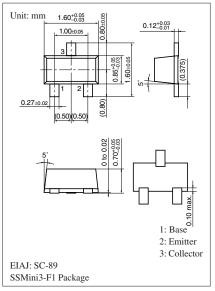
For high-frequency amplification Complementary to 2SC4626J

#### ■ Features

- Optimum for RF amplification of FM/AM radios
- High transition frequency f<sub>T</sub>
- SS-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing

### ■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter                             | Symbol           | Rating      | Unit |  |
|---------------------------------------|------------------|-------------|------|--|
| Collector-base voltage (Emitter open) | V <sub>CBO</sub> | -30         | V    |  |
| Collector-emitter voltage (Base open) | V <sub>CEO</sub> | -20         | V    |  |
| Emitter-base voltage (Collector open) | $V_{EBO}$        | -5          | V    |  |
| Collector current                     | $I_{C}$          | -30         | mA   |  |
| Collector power dissipation           | P <sub>C</sub>   | 125         | mW   |  |
| Junction temperature                  | $T_j$            | 125         | °C   |  |
| Storage temperature                   | $T_{stg}$        | -55 to +125 | °C   |  |



Marking Symbol: E

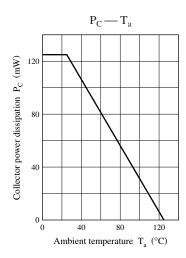
#### $\blacksquare$ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

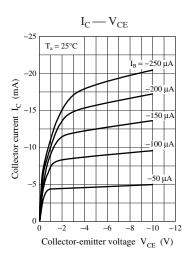
| Parameter                                     | Symbol               | Conditions   | Min | Тур   | Max   | Unit |
|---|----------------------|--|-----|-------|-------|------|
| Base-emitter voltage                          | $V_{BE}$             | $V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$                    |     | - 0.7 |       | V    |
| Collector-base cutoff current (Emitter open)  | $I_{CBO}$            | $V_{CB} = -10 \text{ V}, I_E = 0$                                  |     |       | - 0.1 | μΑ   |
| Collector-emitter cutoff current (Base open)  | $I_{CEO}$            | $V_{CE} = -20 \text{ V}, I_B = 0$                                  |     |       | -100  | μΑ   |
| Emitter-base cutoff current (Collector open)  | $I_{EBO}$            | $V_{EB} = -5 \text{ V}, I_C = 0$                                   |     |       | -10   | μΑ   |
| Forward current transfer ratio *              | h <sub>FE</sub>      | $V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$                    | 70  |       | 220   | _    |
| Collector-emitter saturation voltage          | V <sub>CE(sat)</sub> | $I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$                        |     | - 0.1 |       | V    |
| Transition frequency                          | $f_T$                | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$  | 150 | 300   |       | MHz  |
| Noise figure                                  | NF                   | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 5 \text{ MHz}$    |     | 2.8   | 4.0   | dB   |
| Reverse transfer impedance                    | $Z_{rb}$             | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 2 \text{ MHz}$    |     | 22    | 50    | Ω    |
| Reverse transfer capacitance (Common emitter) | C <sub>re</sub>      | $V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 10.7 \text{ MHz}$ |     | 1.2   | 2.0   | pF   |

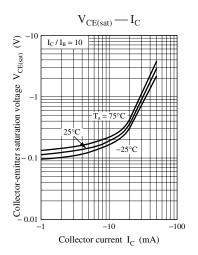
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

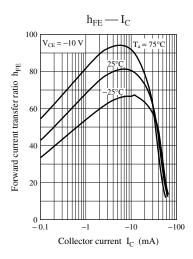
#### 2. \*: Rank classification

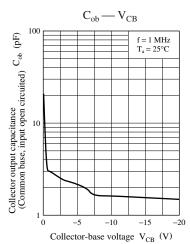
| Rank              | В         | С          |
|-------------------|-----------|------------|
| $h_{\mathrm{FE}}$ | 70 to 140 | 110 to 220 |











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